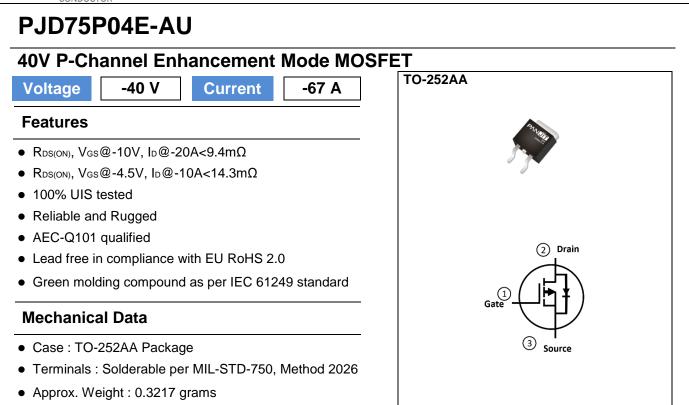
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Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-40	V
Gate-Source Voltage		V _{GS}	±25	
Continuous Drain Current ^(Note 3)	Tc=25°C		-67	
	T _c =100 [°] C	ID	-47	А
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	-228	
Power Dissipation	T _C =25°C	D _	75	10/
	Tc=100°C	Po	38	W
Continuous Drain Current ^(Note 4)	T _A =25°C		-13.3	^
	T _A =70°C	ID	-11	— A
Power Dissipation	T _A =25 [°] C	Po	3	w
	T _A =70 [°] C	PD	2.1	vv
Single Pulse Avalanche Energy ^(Note 5)		Eas	132	mJ
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	2	°C/W
	Junction to Ambient	R _{0JA}	50	



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Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static	4					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-40	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.9	-2.5	
Drain-Source On-State Resistance		V _{GS} =-10V, I _D =-20A	- 7.5 9.4		9.4	
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-10A	-	11	14.3	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-40V, V_{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\pm 25V, V_{DS}=0V$	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Qg		-	59	-	
Gate-Source Charge	Qgs	V _{DS} =-32V, I _D =-20A, V _{GS} =-10V	-	9	-	nC
Gate-Drain Charge	Q_gd	V _{GS} =-10V	-	20	-	
Input Capacitance	Ciss		-	3477	-	pF
Output Capacitance	Coss	V _{DS} =-25V, V _{GS} =0V, f=1MHz	-	377	-	
Reverse Transfer Capacitance	Crss		-	233	-	
Gate resistance	Rg	f=1MHz	-	4	-	Ω
Turn-On Delay Time	td _(on)		-	13	-	
Turn-On Rise Time	tr	V_{DS} =-32V, I_{D} =-20A,	-	16	-]
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =3Ω	-	54	-	ns
Turn-Off Fall Time	tf		-	33	-	
Drain-Source Diode						
Diode Forward Current	I _S	Tc=25°C	-	-	-67	
Pulsed Diode Forward Current	I _{SM}	Tc=25 C	-	-	-228	A
Diode Forward Voltage	V _{SD}	Is=-20A, V _{GS} =0V	-	-0.85	-1.3	V
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =-20A	-	23	-	ns
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	11	-	nC

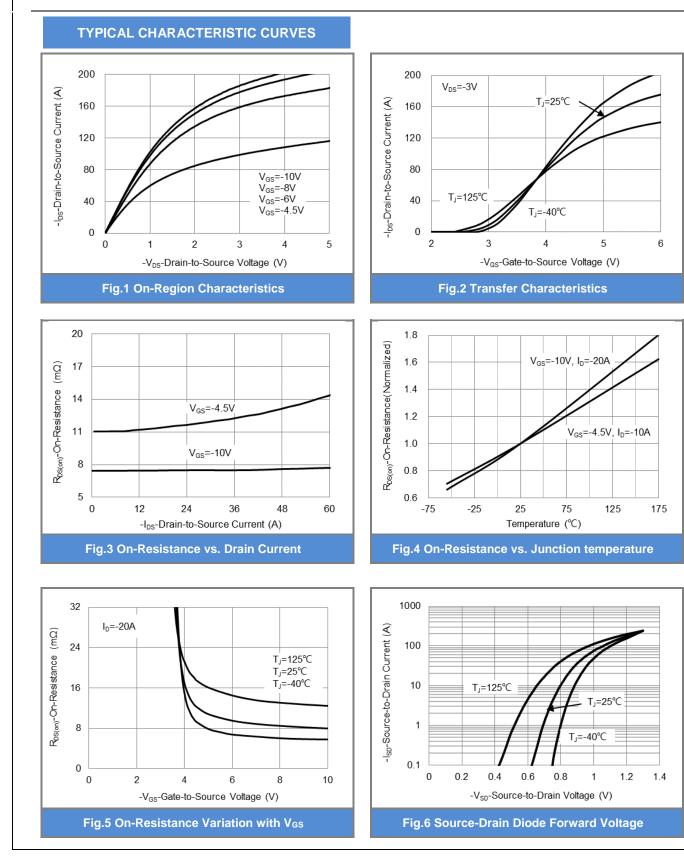
NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =-23A, V_{DD} =-30V, V_{GS} =-10V, Starting T_J =25°C.
- 6. Guaranteed by design, not subject to production testing.

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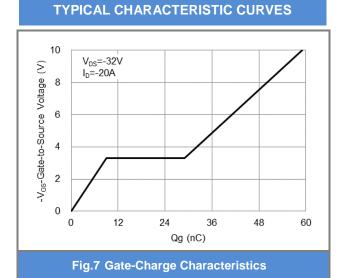


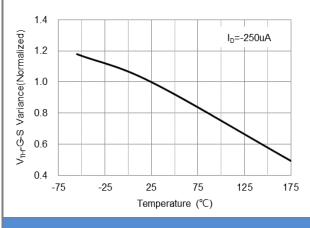
September 11,2023

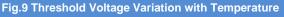
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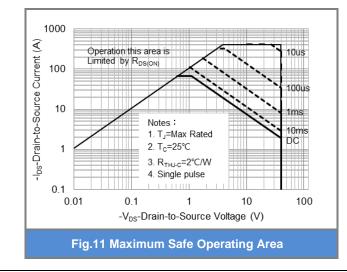
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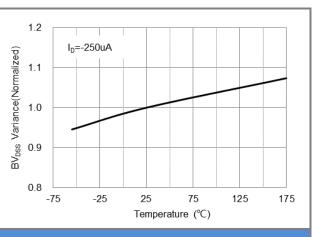
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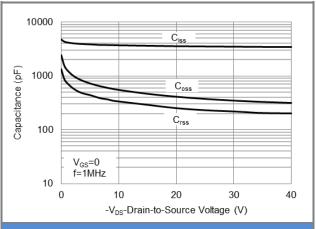
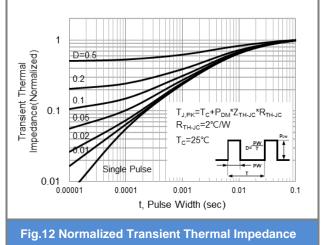


Fig.10 Capacitance vs. Drain-Source Voltage



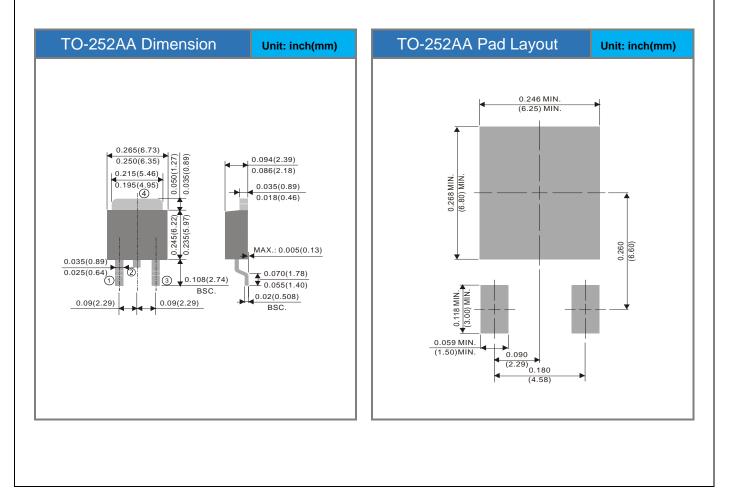


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJD75P04E-AU	TO-252AA	3K pcs / 13" reel	D75P04E	

Packaging Information & Mounting Pad Layout





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